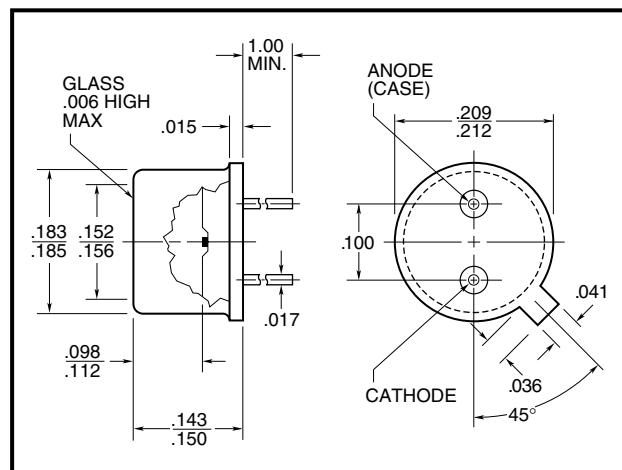




FEATURES

- Selected wavelength range
- Optimized for highest power output
- Other custom wavelengths available
- Very narrow spectral width

All dimensions are nominal values in inches unless otherwise specified.

ELECTRO-OPTICAL CHARACTERISTICS AT 25°C

PARAMETERS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Total Power Output, P_o	$I_F = 100\text{mA}$	10	15		mW
Peak Emission Wavelength, λ_p	$I_F = 20\text{mA}$	770	780	800	nm
Spectral Bandwidth at 50%, $\Delta\lambda$			25		nm
Half Intensity Beam Angle, θ			80		Deg
Forward Voltage, V_F	$I_F = 100\text{mA}$		1.4	1.8	Volts
Reverse Breakdown Voltage, V_R	$I_R = 10\mu\text{A}$	2	5		Volts
Rise Time, T_R			70		nsec
Fall Time, T_F			70		nsec

ABSOLUTE MAXIMUM RATINGS AT 25°C

Power Dissipation	180mW
Continuous Forward Current	100mA
Peak Forward Current (10 μs , 400 Hz)	500mA
Reverse Voltage	2V
Storage and Operating Temperature Range	-55°C to 100°C
Maximum Junction Temperature	100°C
Lead Soldering Temperature (1/16" from case for 10 sec)	240°C